

# **NCE N-Channel Super Trench Power MOSFET**

### **Description**

The NCEP1580GU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

## **Application**

- ●DC/DC Converter
- •Ideal for high-frequency switching and synchronous rectification

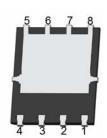
#### **General Features**

- $\bullet$ V<sub>DS</sub> =150V,I<sub>D</sub> =80A R<sub>DS(ON)</sub>=12.0mΩ (typical) @ V<sub>GS</sub>=10V
- ●Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- ●150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

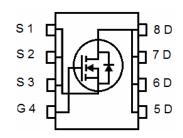
### **DFN 5X6**





Top View

**Bottom View** 



**Schematic Diagram** 

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP1580GU	NCEP1580GU	DFN5X6-8L	-	-	-

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	150	V	
Gate-Source Voltage	V <sub>GS</sub>	±20	V	
Drain Current-Continuous	I <sub>D</sub>	80	А	
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	52	Α	
Pulsed Drain Current	I <sub>DM</sub>	320	Α	
Maximum Power Dissipation	P <sub>D</sub>	160	W	
Derating factor		1.28	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	550	mJ	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}$ C	

#### **Thermal Characteristic**

Thermal Résistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	0.78	°C/W	I
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# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

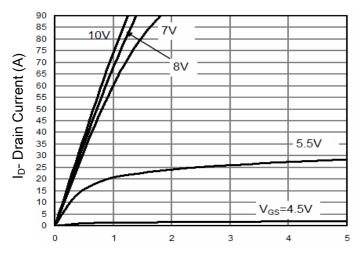
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>		•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	150	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.0		4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	12	14.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =40A	-	58	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	\\ 75\\\\ 0\\	-	2200	2700	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =75V,V <sub>GS</sub> =0V, F=1.0MHz	-	289	450	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0lvlm2	-	11.2	18	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	12.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =75V, $I_D$ =40A $V_{GS}$ =10V, $R_G$ =3 $\Omega$	-	3.8	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	14	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.5	-	nS
Total Gate Charge	Qg	\/ -75\/  -40A	-	33	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =75 $V$ , $I_{D}$ =40 $A$ , $V_{GS}$ =10 $V$	-	14.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	8	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = 40A$	-	47	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	55	-	nC

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec. The value of  $R_{8JA}$  is measured with the device mounted on  $1in^2$  FR-4 board with 2oz. Copper, in a still air environment with  $T_A$  =25° C. the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

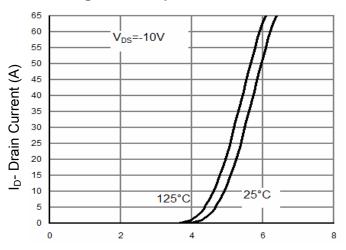


# **Typical Electrical and Thermal Characteristics**



Vds Drain-Source Voltage (V)

**Figure 1 Output Characteristics** 



Vgs Gate-Source Voltage (V)

**Figure 2 Transfer Characteristics** 

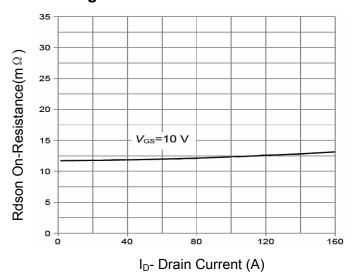
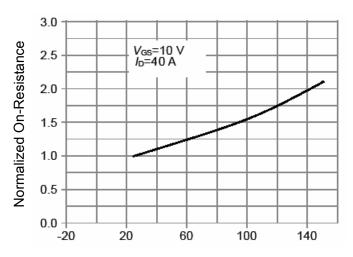


Figure 3 Rdson- Drain Current



T<sub>J</sub>-Junction Temperature(°C)

**Figure 4 Rdson-Junction Temperature** 

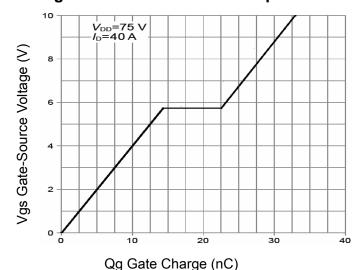
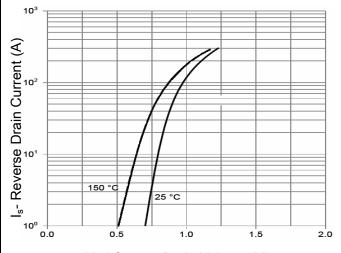


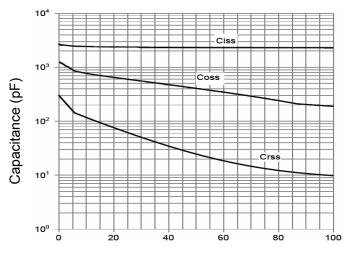
Figure 5 Gate Charge



Vsd Source-Drain Voltage (V)

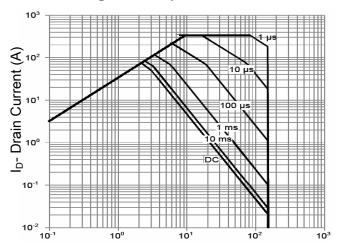
Figure 6 Source- Drain Diode Forward





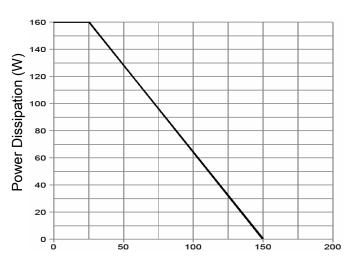
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



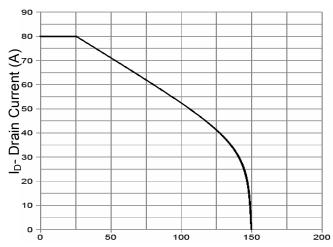
Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



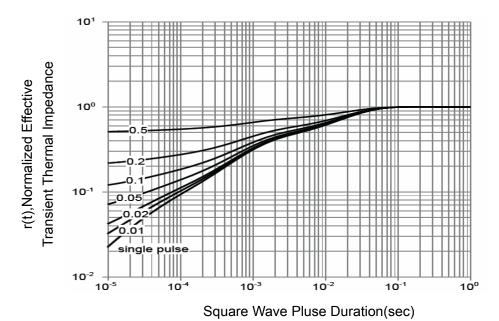
 $T_C$ -Case Temperature( $^{\circ}C$ )

# Figure 9 Power De-rating



 $T_C$ -Case Temperature (°C)

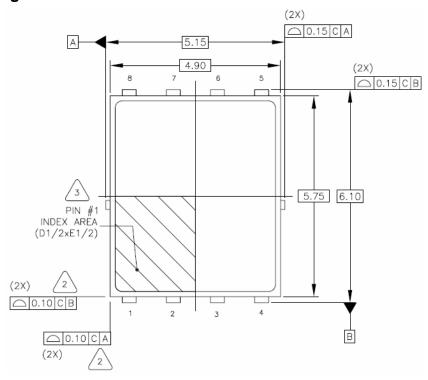
Figure 10 Current De-rating

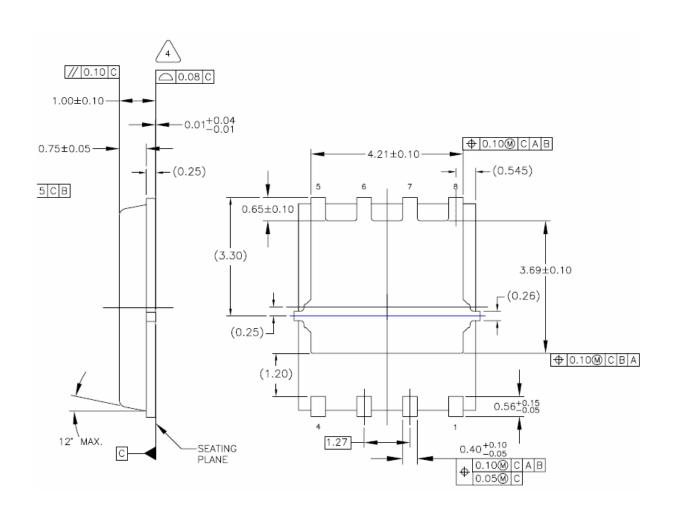


**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **DFN5X6-8L Package Information**





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# NCEP1580GU

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